# NSN 5962-01-234-3569

Memory Microcircuit - Page 1 of 2



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# Body Length: 1.485 inches Body Width: Between 0.590 inches and 0.625 inches Body Height:

0.217 inches

# **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### End Application:

Alq176 mlv

#### Features Provided:

Hermetically sealed and burn in and w/enable and ultraviolet erasable and programmable

#### Inclosure Material:

Ceramic

# **Inclosure Configuration:**

Dual-in-line

# Output Logic Form:

N-type metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

17 input

# **Current Rating Per Characteristic:**

50.00 milliamperes total supply

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

6.5 volts power source

# **Time Rating Per Chacteristic:**

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level

output

#### Memory Device Type:

Prom

#### **Memory Capacity:**

Unknown

# **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

28 printed circuit

#### Shelf Life:

N/a

# NSN 5962-01-234-3569

Memory Microcircuit - Page 2 of 2

Unit Of Measure:

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Demilitarization:

No

Fiig:

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